



FIN1531MTCX

5V LVDS 4-Bit High Speed Differential Driver

This quad driver is designed for high speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. The driver translates 5V TTL/CMOS signal levels to LVDS levels with a typical differential output swing of 350 mV which provides low EMI at ultra low power dissipation even at high frequencies. This device is ideal for high speed transfer of clock and data.

The FIN1531 can be paired with its companion receiver, the FIN1532, or with any other Fairchild LVDS receiver.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer (OCM).

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

FOR REFERENCE ONLY

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FIN1531 5V LVDS 4-Bit High Speed Differential Driver

FAIRCHILD

SEMICONDUCTOR

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General Description

This quad driver is designed for high speed interconnects utilizing Low Voltage Differential Signaling (LVDS) technology. The driver translates 5V TTL/CMOS signal levels to LVDS levels with a typical differential output swing of 350 mV which provides low EMI at ultra low power dissipation even at high frequencies. This device is ideal for high speed transfer of clock and data.

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Features

- Greater than 400Mbs data rate
- 5V power supply operation
- 400ps max differential pulse skew
- 2.0ns maximum propagation delay
- Low power dissipation
- Power-Off protection
- Meets or exceeds the TIA/EIA-644 LVDS standard
- Pin compatible with equivalent RS-422 and PECL devices
- 16-Lead SOIC and TSSOP packages save space

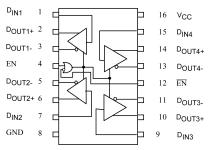
Ordering Code:

Order Number	Package Number	Package Description
FIN1531M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
FIN1531MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
Devices also available	in Tape and Reel. Specify	by appending the suffix letter "X" to the ordering code.

Function Table

Input			Out	puts
EN	EN	D _{IN}	D _{OUT+}	D _{OUT-}
Н	Х	Н	Н	L
Н	Х	L	L	н
Н	Х	OPEN	L	Н
Х	L	Н	Н	L
Х	L	L	L	Н
Х	L	OPEN	L	Н
L	Н	Х	Z	Z





X = Don't Care

Pin Descriptions

Pin Name	Description
D _{IN1} , D _{IN2} , D _{IN3} , D _{IN4}	5V TTL/CMOS Data Input
D _{OUT1+} , D _{OUT2} +, D _{OUT3+} , D _{OUT4+}	Non-inverting LVDS Output
D _{OUT1-} , D _{OUT2-} , D _{OUT3-} , D _{OUT4-}	Inverting LVDS Output
EN	Driver Enable Pin
EN	Inverting Driver Enable Pin
V _{CC}	Power Supply
GND	Ground

Absolute Maximum Ratings(Note 1)

Supply Voltage (V _{CC})	-0.5V to +6V
DC Input Voltage (VIN)	-0.5V to +6V
DC Output Voltage (V _{OUT})	-0.5V to +6V
Driver Short Circuit Current (IOSD)	Continuous
Storage Temperature Range (T _{STG})	$-65^{\circ}C$ to $+150^{\circ}C$
Max Junction Temperature (T _J)	150°C
Lead Temperature (T _L)	
(Soldering, 10 seconds)	260°C
ESD (Human Body Model)	≥ 8000V
ESD (Machine Model)	≥ 400V

Recommended Operating Conditions

Supply Voltage (V _{CC})	4.5V to 5.5V
Input Voltage (V _{IN})	0 to V _{CC}
Operating Temperature (T _A)	-40°C to +85°C

Note 1: The "Absolute Maximum Ratings": are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature and output/input loading variables. Fairchild does not recommend operation of circuits outside databook specification.

DC Electrical Characteristics

Over supply voltage and operating temperature ranges, unless otherwise specified

Symbol	Parameter	Test Conditions	Min	Typ (Note 2)	Max	Units
V _{OD}	Output Differential Voltage		250	350	450	mV
ΔV_{OD}	V _{OD} Magnitude Change from Differential LOW-to-HIGH	RL = 100Ω, driver enabled, See Figure 1			25	mV
V _{OS}	Offset Voltage	=	1.125	1.25	1.375	V
ΔV _{OS}	Offset Magnitude Change from Differential LOW-to-HIGH				25	mV
IOFF	Power Off Output Current	$V_{CC} = 0V, V_{OUT} = 5.5V$			50	μA
I _{OS}	Short Circuit Output Current	V _{OUT} = 0V, Driver Enabled			-6	mA
		V _{OD} = 0V, Driver Enabled			±6	
VIH	Input HIGH Voltage		2.0		V _{CC}	V
VIL	Input LOW Voltage		GND		0.8	V
I _{IN}	Input Current	$V_{IN} = 0V \text{ or } V_{CC}$			±20	μΑ
I _{I(OFF)}	Power-OFF Input Current	$V_{CC} = 0V, V_{IN} = 5.5V$			50	μΑ
I _{OZ}	Disabled Output Leakage Current	EN = 0.8V, EN = 2.0V, V _{OUT} = 0V or 7V			±20	μΑ
V _{IK}	Input Clamp Voltage	I _{IK} = -18 mA	-1.5	-0.8		V
Icc	Power Supply Current	No Load, $V_{IN} = 0V$ or V_{CC} , Driver Enabled		3.3	6	
		$R_L = 100\Omega$, Driver Disabled		3.4	6	mA
		R_L = 100Ω, V_{IN} = 0V or $V_{CC},$ Driver Enabled		18	26	
C _{IN}	Input Capacitance			7		pF
COUT	Output Capacitance			4.5		pF

Note 2: All typical values are at T_A = 25°C and with V_{CC} = 5.0V.

Symbol	Parameter	Test Conditions	Min	Typ (Note 3)	Max	Units
t _{PLHD}	Differential Propagation Delay LOW-to-HIGH		0.5	1.4	2.0	ns
t _{PHLD}	Differential Propagation Delay HIGH-to-LOW	R_L = 100 Ω, C_L = 10 pF,	0.5	1.4	2.0	ns
t _{TLHD}	Differential Output Rise Time (20% to 80%)	See Figure 2 and Figure 3 (Note 7)	0.6	0.8	1.2	ns
t _{THLD}	Differential Output Fall Time (80% to 20%)	1	0.6	0.8	1.2	ns
t _{SK(P)}	Pulse Skew t _{PLH} - t _{PHL}	1			0.4	ns
t _{SK(LH)} , t _{SK(HL)}	Channel-to-Channel Skew (Note 4)				0.3	ns
t _{SK(PP)}	Part-to-Part Skew (Note 5)	1		1 1	1.0	ns
f _{MAX}	Maximum Frequency(Note 6)	Ī	200	250		ns
t _{ZHD}	LVTTL Output Enable Time from Z to HIGH	$R_L = 100\Omega$, $C_L = 10 \text{ pF}$,			5.0	ns
t _{ZLD}	LVTTL Output Enable Time from Z to LOW	See Figure 4 and Figure 5 (Note 7)		1	5.0	ns
t _{HZD}	LVTTL Output Disable Time from HIGH to Z	Ī			5.0	ns
t _{LZD}	LVTTL Output Disable Time from LOW to Z	1 F		1	5.0	ns

Note 3: All typical values are at T_A = 25°C and with V_{CC} = 5V.

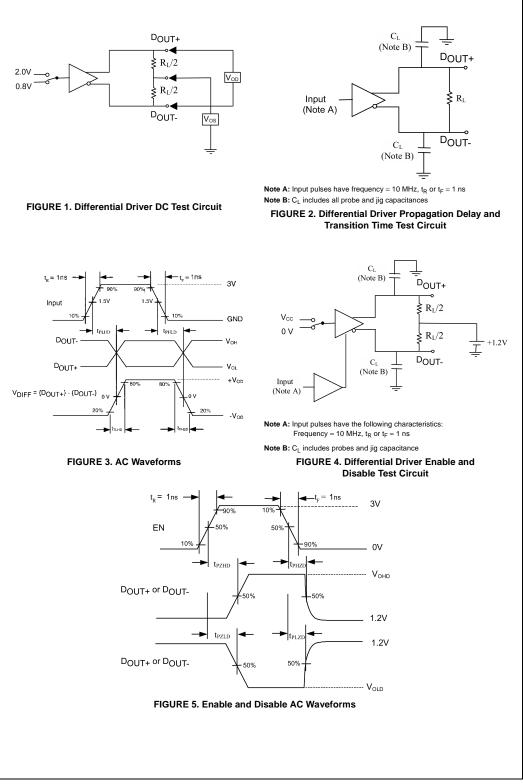
Note 4: $t_{SK(LH)}$, $t_{SK(HL)}$ is the skew between specified outputs of a single device when the outputs have identical loads and are switching in the same direction.

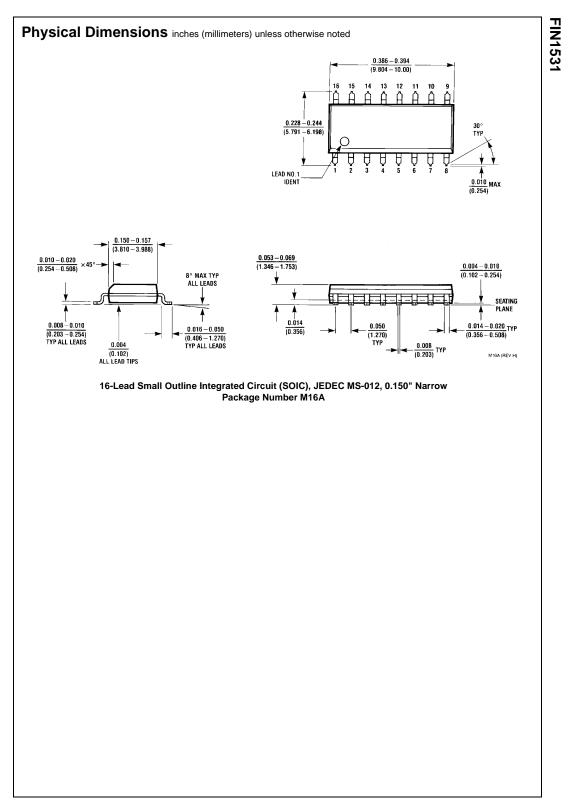
Note 5: $t_{SK(PP)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices switching in the same direction (either LOW-to-HIGH or HIGH-to-LOW) when both devices operate with the same supply voltage, same temperature, and have identical test circuits. Note 6: f_{MAX} Criteria: Input $t_R = t_F < 1$ ns, 0V to 3V, 50% Duty Cycle; Output $V_{OD} > 250$ mV, 45% to 55% Duty Cycle; all output channels switching in phase.

Note 7: Test Circuits in Figure 2 and Figure 4 are simplified representations of test fixture and DUT loading.

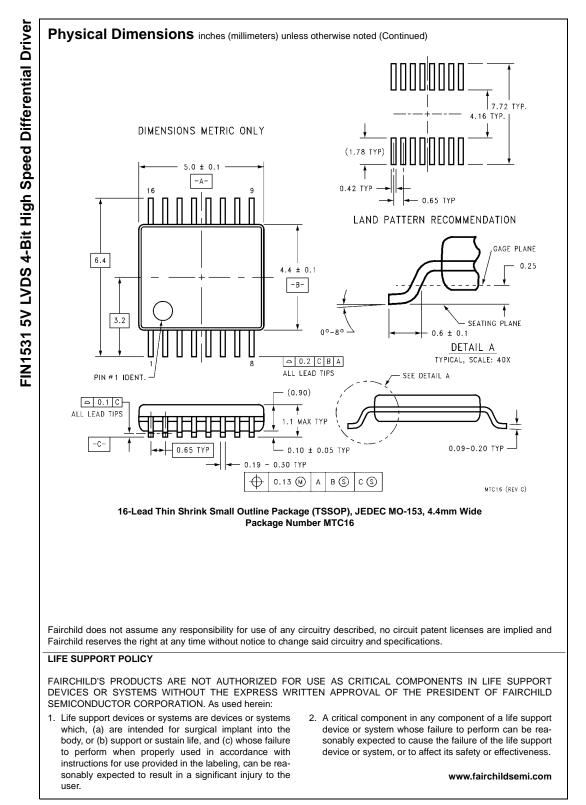
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